

Quad 16-/14-/12-Bit *nano*DAC+ with 2 ppm/°C Reference, I²C Interface

Data Sheet

AD5696R/AD5695R/AD5694R

FEATURES

High relative accuracy (INL): ±2 LSB maximum @ 16 bits

Low drift 2.5 V reference: 2 ppm/°C typical Tiny package: 3 mm × 3 mm, 16-lead LFCSP

Total unadjusted error (TUE): ±0.1% of FSR maximum

Offset error: ±1.5 mV maximum Gain error: ±0.1% of FSR maximum

High drive capability: 20 mA, 0.5 V from supply rails

User selectable gain of 1 or 2 (GAIN pin) Reset to zero scale or midscale (RSTSEL pin)

1.8 V logic compatibility Low glitch: 0.5 nV-sec

400 kHz I²C-compatible serial interface

Robust 3.5 kV HBM and 1.5 kV FICDM ESD rating

Low power: 3.3 mW at 3 V 2.7 V to 5.5 V power supply

-40°C to +105°C temperature range

APPLICATIONS

Optical transceivers Base-station power amplifiers Process control (PLC I/O cards) **Industrial automation Data acquisition systems**

GENERAL DESCRIPTION

The AD5696R/AD5695R/AD5694R family, are low power, quad, 16-/14-/12-bit buffered voltage output DACs. The devices include a 2.5 V, 2 ppm/°C internal reference (enabled by default) and a gain select pin giving a full-scale output of 2.5 V (gain = 1) or 5 V (gain = 2). All devices operate from a single 2.7 V to 5.5 V supply, are guaranteed monotonic by design, and exhibit less than 0.1% FSR gain error and 1.5 mV offset error performance. The devices are available in a 3 mm \times 3 mm LFCSP and a TSSOP package.

The AD5696R/AD5695R/AD5694R also incorporate a poweron reset circuit and a RSTSEL pin that ensures that the DAC outputs power up to zero scale or midscale and remain there until a valid write takes place. Each part contains a per-channel power-down feature that reduces the current consumption of the device to $4 \mu A$ at 3 V while in power-down mode.

The AD5696R/AD5695R/AD5694R use a versatile 2-wire serial interface that operates at clock rates up to 400 kHz, and includes a V_{LOGIC} pin intended for 1.8 V/3 V/5 V logic.

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FUNCTIONAL BLOCK DIAGRAM

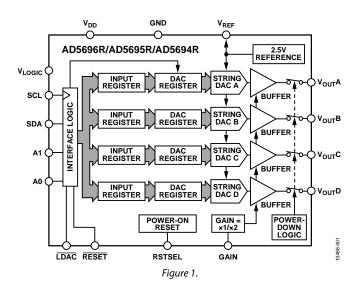


Table 1. Quad nanoDAC+ Devices

Interface	Reference	16-Bit	14-Bit	12-Bit
SPI	Internal	AD5686R	AD5685R	AD5684R
I^2C	Internal	AD5696R	AD5695R	AD5694R

PRODUCT HIGHLIGHTS

High Relative Accuracy (INL).

AD5696R (16-bit): ±2 LSB maximum AD5695R (14-bit): ±1 LSB maximum AD5694R (12-bit): ±1 LSB maximum

Low Drift 2.5 V On-Chip Reference.

2 ppm/°C typical temperature coefficient 5 ppm/°C maximum temperature coefficient

Two Package Options.

3 mm × 3 mm, 16-lead LFCSP 16-lead TSSOP

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Data Sheet

AD5696R/AD5695R/AD5694R

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REVISION HISTORY

4/12—Revision 0: Initial Version

SPECIFICATIONS

 $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}; 1.8 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}; \text{ all specifications } T_{MIN} \text{ to } T_{MAX} \text{, unless otherwise noted. } R_L = 2 \text{ k}\Omega; C_L = 200 \text{ pF.}$

Table 2.

		A Grade	1		B Grade	1		
Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions/Comments
STATIC PERFORMANCE ²								
AD5696R								
Resolution	16			16			Bits	
Relative Accuracy		±2	±8		±1	±2	LSB	Gain = 2
		±2	±8		±1	±3		Gain = 1
Differential Nonlinearity			±1			±1	LSB	Guaranteed monotonic by design
AD5695R								
Resolution	14			14			Bits	
Relative Accuracy		±0.5	±4		±0.5	±1	LSB	
Differential Nonlinearity			±1			±1	LSB	Guaranteed monotonic by design
AD5694R								, ,
Resolution	12			12			Bits	
Relative Accuracy		±0.12	±2		±0.12	±1	LSB	
Differential Nonlinearity			±1			±1	LSB	Guaranteed monotonic by design
Zero-Code Error		0.4	4		0.4	1.5	mV	All zeros loaded to DAC register
Offset Error		+0.1	±4		+0.1	±1.5	mV	/ 20.03 .04404 to 27.10 register
Full-Scale Error		+0.01	±0.2		+0.01	±0.1	% of	All ones loaded to DAC register
rail scale Error		10.01	±0.2		10.01	±0.1	FSR	7 in ones louded to brie register
Gain Error		±0.02	±0.2		±0.02	±0.1	% of FSR	
Total Unadjusted Error		±0.01	±0.25		±0.01	±0.1	% of FSR	External reference; gain = 2; TSSOP
			±0.25			±0.2	% of FSR	Internal reference; gain = 1; TSSOP
Offset Error Drift ³		±1			±1		μV/°C	
Gain Temperature Coefficient ³		±1			±1		ppm	Of FSR/°C
DC Power Supply Rejection Ratio ³		0.15			0.15		mV/V	DAC code = midscale; $V_{DD} = 5 \text{ V} \pm 10\%$
DC Crosstalk ³								
		±2			±2		μV	Due to single channel, full-scale output change
		±3			±3		μV/mA	Due to load current change
		±2			±2		μV	Due to powering down (per channel)
OUTPUT CHARACTERISTICS ³							'	,
Output Voltage Range	0		V_{REF}	0		V_{REF}	V	Gain = 1
output voltage hange	0		2 × V _{REF}	0		2 × V _{REF}	V	Gain = 2, see Figure 31
Capacitive Load Stability		2	Z / VIII		2	Z.X VILI	nF	$R_L = \infty$
capacitive Load Stability		10			10		nF	$R_L = 1 \text{ k}\Omega$
Resistive Load ⁴	1	10		1	10		kΩ	11 - 1 122
Load Regulation	'	80		!	80		μV/mA	$5 \text{ V} \pm 10\%$, DAC code = midscale;
Load Negulation							'	-30 mA ≤ I _{OUT} ≤ 30 mA
		80			80		μV/mA	3 V ± 10%, DAC code = midscale; −20 mA ≤ I_{OUT} ≤ 20 mA
Short-Circuit Current ⁵		40			40		mA	
Load Impedance at Rails ⁶		25			25		Ω	See Figure 31
Power-Up Time		2.5			2.5		μs	Coming out of power-down mode; $V_{DD} = 5 \text{ V}$

		A Grade	2 ¹		B Grade	<u>1</u>						
Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions/Comments				
REFERENCE OUTPUT												
Output Voltage ⁷	2.4975		2.5025	2.4975		2.5025	V	At ambient				
Reference TC ^{8, 9}		5	20		2	5	ppm/°C	See the Terminology section				
Output Impedance ³		0.04			0.04		Ω					
Output Voltage Noise ³		12			12		μV p-p	0.1 Hz to 10 Hz				
Output Voltage Noise Density ³		240			240		nV/√Hz	At ambient; $f = 10 \text{ kHz}$, $C_L = 10 \text{ nF}$				
Load Regulation Sourcing ³		20			20		μV/mA	At ambient				
Load Regulation Sinking ³		40			40		μV/mA	At ambient				
Output Current Load Capability ³		±5			±5		mA	V _{DD} ≥ 3 V				
Line Regulation ³		100			100		μV/V	At ambient				
Long-Term Stability/Drift ³		12			12		ppm	After 1000 hours at 125°C				
Thermal Hysteresis ³		125			125		ppm	First cycle				
, , , , , , , , , , , , , , , , , , , ,		25			25		ppm	Additional cycles				
LOGIC INPUTS ³								,				
Input Current			±2			±2	μΑ	Per pin				
V _{INL} , Input Low Voltage			$0.3 \times V_{LOGIC}$			$0.3 \times V_{LOGIC}$	V					
V _{INH} , Input High Voltage	$0.7 \times V_{LOGIC}$			$0.7 \times V_{LOGIC}$			V					
Pin Capacitance		2			2		pF					
LOGIC OUTPUTS (SDA) ³												
Output Low Voltage, Vol			0.4			0.4	V	$I_{SINK} = 3 \text{ mA}$				
Floating State Output Capacitance		4			4		pF					
POWER REQUIREMENTS												
V_{LOGIC}	1.8		5.5	1.8		5.5	V					
I _{LOGIC}			3			3	μΑ					
V_{DD}	2.7		5.5	2.7		5.5	V	Gain = 1				
V_{DD}	$V_{REF} + 1.5$		5.5	$V_{REF} + 1.5$		5.5	V	Gain = 2				
I_{DD}								$V_{IH} = V_{DD}$, $V_{IL} = GND$, $V_{DD} = 2.7 \text{ V to } 5.5$				
Normal Mode ¹⁰		0.59	0.7		0.59	0.7	mA	Internal reference off				
		1.1	1.3		1.1	1.3	mA	Internal reference on, at full scale				
All Power-Down Modes ¹¹		1	4		1	4	μΑ	−40°C to +85°C				
			6			6	μΑ	-40°C to +105°C				

¹ Temperature range: A and B grade: −40°C to +105°C.

 $^{^2}$ DC specifications tested with the outputs unloaded, unless otherwise noted. Upper dead band = 10 mV and exists only when $V_{REF} = V_{DD}$ with gain = 1 or when $V_{REF}/2 = V_{DD}$ with gain = 2. Linearity calculated using a reduced code range of 256 to 65,280 (AD5696R), 64 to 16,320 (AD5695R), and 12 to 4080 (AD5694R).

³ Guaranteed by design and characterization; not production tested.

⁴ Channel A and Channel B can have a combined output current of up to 30 mA. Similarly, Channel C and Channel D can have a combined output current of up to 30 mA up to a junction temperature of 110°C.

⁵ V_{DD} = 5 V. The device includes current limiting that is intended to protect the device during temporary overload conditions. Junction temperature can be exceeded during current limit. Operation above the specified maximum operation junction temperature may impair device reliability.

⁶ When drawing a load current at either rail, the output voltage headroom with respect to that rail is limited by the 25 Ω typical channel resistance of the output devices. For example, when sinking 1 mA, the minimum output voltage = $25 \Omega \times 1 \text{ mA} = 25 \text{ mV}$ (see Figure 31).

⁷ Initial accuracy presolder reflow is ±750 µV; output voltage includes the effects of preconditioning drift. See the Internal Reference Setup section.

⁸ Reference is trimmed and tested at two temperatures and is characterized from -40°C to +105°C.

⁹ Reference temperature coefficient calculated as per the box method. See the Terminology section for further information.

 $^{^{\}rm 10}$ Interface inactive. All DACs active. DAC outputs unloaded.

¹¹ All DACs powered down.

AC CHARACTERISTICS

 $V_{DD} = 2.7 \text{ V}$ to 5.5 V; $R_L = 2 \text{ k}\Omega$ to GND; $C_L = 200 \text{ pF}$ to GND; $1.8 \text{ V} \le V_{LOGIC} \le 5.5 \text{ V}$; all specifications T_{MIN} to T_{MAX} , unless otherwise noted.1

Table 3.

Parameter ²	Min	Тур	Max	Unit	Test Conditions/Comments ³
Output Voltage Settling Time					
AD5696R		5	8	μs	1/4 to 3/4 scale settling to ±2 LSB
AD5695R		5	8	μs	1/4 to 3/4 scale settling to ±2 LSB
AD5694R		5	7	μs	1/4 to 3/4 scale settling to ±2 LSB
Slew Rate		0.8		V/µs	
Digital-to-Analog Glitch Impulse		0.5		nV-sec	1 LSB change around major carry
Digital Feedthrough		0.13		nV-sec	
Digital Crosstalk		0.1		nV-sec	
Analog Crosstalk		0.2		nV-sec	
DAC-to-DAC Crosstalk		0.3		nV-sec	
Total Harmonic Distortion⁴		-80		dB	At ambient, BW = 20 kHz, V_{DD} = 5 V, f_{OUT} = 1 kHz
Output Noise Spectral Density		300		nV/√Hz	DAC code = midscale, 10 kHz; gain = 2
Output Noise		6		μV p-p	0.1 Hz to 10 Hz
SNR		90		dB	At ambient, BW = 20 kHz, V_{DD} = 5 V, f_{OUT} = 1 kHz
SFDR		83		dB	At ambient, BW = 20 kHz, V_{DD} = 5 V, f_{OUT} = 1 kHz
SINAD		80		dB	At ambient, BW = 20 kHz, V_{DD} = 5 V, f_{OUT} = 1 kHz

 $^{^{\}rm 1}$ Guaranteed by design and characterization; not production tested. $^{\rm 2}$ See the Terminology section.

 $^{^3}$ Temperature range is -40° C to $+105^{\circ}$ C, typical @ 25°C. 4 Digitally generated sine wave @ 1 kHz.

TIMING CHARACTERISTICS

 V_{DD} = 2.5 V to 5.5 V; 1.8 V \leq V_{LOGIC} \leq 5.5 V; all specifications T_{MIN} to T_{MAX} , unless otherwise noted. ¹

Table 4.

Parameter ²	Min	Max	Unit	Conditions/Comments
t ₁	2.5		μs	SCL cycle time
t_2	0.6		μs	t _{ніGH} , SCL high time
t ₃	1.3		μs	t _{LOW} , SCL low time
t ₄	0.6		μs	thd,sta, start/repeated start condition hold time
t ₅	100		ns	t _{SU,DAT} , data setup time
t_6 ³	0	0.9	μs	t _{HD,DAT} , data hold time
t ₇	0.6		μs	t _{SU,STA} , setup time for repeated start
t ₈	0.6		μs	t _{SU,STO} , stop condition setup time
t ₉	1.3		μs	t _{BUF} , bus free time between a stop and a start condition
t ₁₀	0	300	ns	t_{R_r} rise time of SCL and SDA when receiving
t ₁₁	$20 + 0.1C_{B}^{4}$	300	ns	t _F , fall time of SDA and SCL when transmitting/ receiving
t ₁₂	20		ns	LDAC pulse width
t ₁₃	400		ns	SCL rising edge to LDAC rising edge
C_B^4		400	рF	Capacitive load for each bus line

¹ See Figure 2.

 $^{^4}$ C_B is the total capacitance of one bus line in pF. t_R and t_F measured between 0.3 V_{DD} and 0.7 V_{DD} .

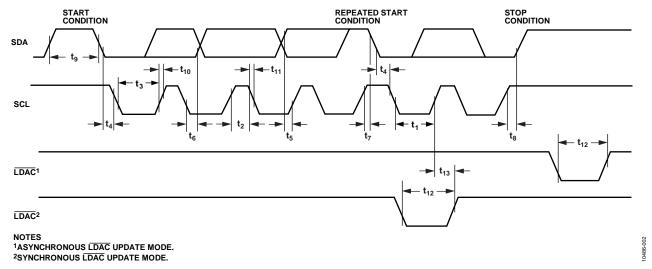


Figure 2. 2-Wire Serial Interface Timing Diagram

² Guaranteed by design and characterization; not production tested.

³ A master device must provide a hold time of at least 300 ns for the SDA signal (referred to the V_H min of the SCL signal) to bridge the undefined region of SCL's falling edge.

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 5.

Parameter Rating V _{DD} to GND −0.3 V to +7 V V _{LOGIC} to GND −0.3 V to +7 V V _{OUT} to GND −0.3 V to V _{DD} + 0.3 V V _{REF} to GND −0.3 V to V _{DD} + 0.3 V Digital Input Voltage to GND¹ −0.3 V to V _{LOGIC} + 0.3 V SDA and SCL to GND −0.3 V to +7 V Operating Temperature Range −40°C to +105°C
$\begin{array}{lll} V_{LOGIC} \ to \ GND & -0.3 \ V \ to \ +7 \ V \\ V_{OUT} \ to \ GND & -0.3 \ V \ to \ V_{DD} \ +0.3 \ V \\ V_{REF} \ to \ GND & -0.3 \ V \ to \ V_{DD} \ +0.3 \ V \\ Digital \ Input \ Voltage \ to \ GND^1 & -0.3 \ V \ to \ V_{LOGIC} \ +0.3 \ V \\ SDA \ and \ SCL \ to \ GND & -0.3 \ V \ to \ +7 \ V \end{array}$
$\begin{array}{lll} V_{\text{OUT}} \text{ to GND} & -0.3 \text{ V to V}_{\text{DD}} + 0.3 \text{ V} \\ V_{\text{REF}} \text{ to GND} & -0.3 \text{ V to V}_{\text{DD}} + 0.3 \text{ V} \\ Digital Input Voltage to GND^1 & -0.3 \text{ V to V}_{\text{LOGIC}} + 0.3 \text{ V} \\ \text{SDA and SCL to GND} & -0.3 \text{ V to +7 V} \end{array}$
$\begin{array}{lll} V_{REF} \ to \ GND & -0.3 \ V \ to \ V_{DD} + 0.3 \ V \\ Digital \ Input \ Voltage \ to \ GND^1 & -0.3 \ V \ to \ V_{LOGIC} + 0.3 \ V \\ SDA \ and \ SCL \ to \ GND & -0.3 \ V \ to \ +7 \ V \end{array}$
Digital Input Voltage to GND ¹ $-0.3 \text{ V to V}_{\text{LOGIC}} + 0.3 \text{ V}$ SDA and SCL to GND -0.3 V to +7 V
SDA and SCL to GND -0.3 V to +7 V
Operating Temperature Range -40°C to +105°C
Storage Temperature Range –65°C to +150°C
Junction Temperature 125°C
16-Lead TSSOP, θ _{JA} Thermal 112.6°C/W
Impedance, 0 Airflow (4-Layer Board)
16-Lead LFCSP, θ _{JA} Thermal 70°C/W
Impedance, 0 Airflow (4-Layer Board)
Reflow Soldering Peak 260°C
Temperature, Pb Free (J-STD-020)
ESD ² 3.5 kV
FICDM 1.5 kV

¹ Excluding SDA and SCL.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

² Human body model (HBM) classification.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



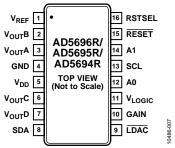


Figure 4. 16-Lead TSSOP Pin Configuration

Table 6. Pin Function Descriptions

P	Pin No.		
LFCSP	TSSOP	Mnemonic	Description
1	3	V _{OUT} A	Analog Output Voltage from DAC A. The output amplifier has rail-to-rail operation.
2	4	GND	Ground Reference Point for All Circuitry on the Part.
3	5	V _{DD}	Power Supply Input. These parts can be operated from 2.7 V to 5.5 V, and the supply should be decoupled with a 10 μ F capacitor in parallel with a 0.1 μ F capacitor to GND.
4	6	V _{OUT} C	Analog Output Voltage from DAC C. The output amplifier has rail-to-rail operation.
5	7	VoutD	Analog Output Voltage from DAC D. The output amplifier has rail-to-rail operation.
6	8	SDA	Serial Data Input. This pin is used in conjunction with the SCL line to clock data into or out of the 24-bit input shift register. SDA is a bidirectional, open-drain data line that should be pulled to the supply with an external pull-up resistor.
7	9	LDAC	LDAC can be operated in two modes, asynchronously and synchronously. Pulsing this pin low allows any or all DAC registers to be updated if the input registers have new data. This allows all DAC outputs to simultaneously update. This pin can also be tied permanently low.
8	10	GAIN	Span Set Pin. When this pin is tied to GND, all four DAC outputs have a span from 0 V to V_{REF} . If this pin is tied to V_{DD} , all four DACs output a span of 0 V to 2 \times V_{REF} .
9	11	V_{LOGIC}	Digital Power Supply. Voltage ranges from 1.8 V to 5.5 V.
10	12	A0	Address Input. Sets the first LSB of the 7-bit slave address.
11	13	SCL	Serial Clock Line. This is used in conjunction with the SDA line to clock data into or out of the 24-bit input register.
12	14	A1	Address Input. Sets the second LSB of the 7-bit slave address.
13	15	RESET	Asynchronous Reset Input. The RESET input is falling edge sensitive. When RESET is low, all LDAC pulses are ignored. When RESET is activated, the input register and the DAC register are updated with zero scale or midscale, depending on the state of the RSTSEL pin.
14	16	RSTSEL	Power-On Reset Pin. Tying this pin to GND powers up all four DACs to zero scale. Tying this pin to VDD powers up all four DACs to midscale.
15	1	V _{REF}	Reference Voltage. The AD5696R/AD5695R/AD5694R have a common reference pin. When using the internal reference, this is the reference output pin. When using an external reference, this is the reference input pin. The default for this pin is as a reference output.
16	2	V _{оит} В	Analog Output Voltage from DAC B. The output amplifier has rail-to-rail operation.
17	N/A	EPAD	Exposed Pad. The exposed pad must be tied to GND.

TYPICAL PERFORMANCE CHARACTERISTICS

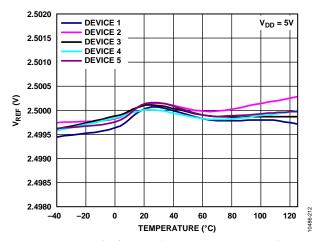


Figure 5. Internal Reference Voltage vs. Temperature (Grade B)

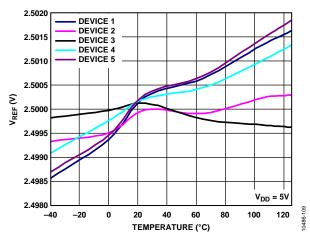


Figure 6. Internal Reference Voltage vs. Temperature (Grade A)

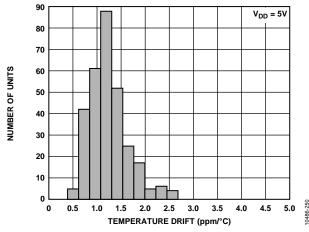


Figure 7. Reference Output Temperature Drift Histogram

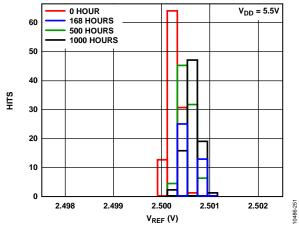


Figure 8. Reference Long-Term Stability/Drift

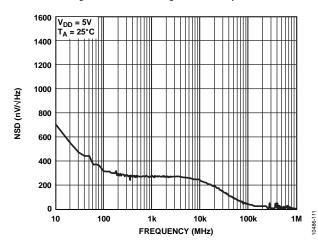


Figure 9. Internal Reference Noise Spectral Density vs. Frequency

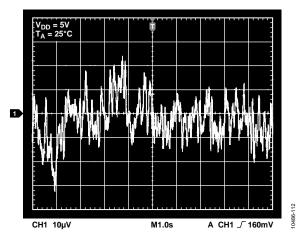


Figure 10. Internal Reference Noise, 0.1 Hz to 10 Hz

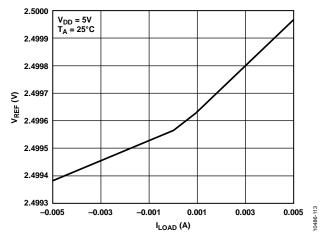


Figure 11. Internal Reference Voltage vs. Load Current

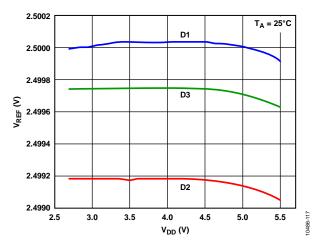


Figure 12. Internal Reference Voltage vs. Supply Voltage

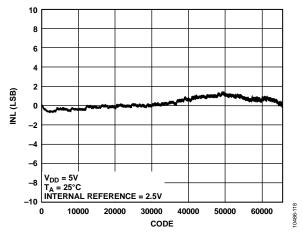


Figure 13. AD5696R INL

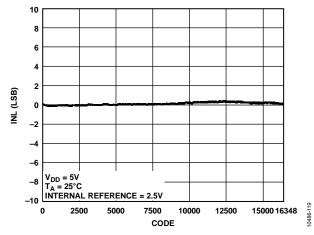


Figure 14. AD5695R INL

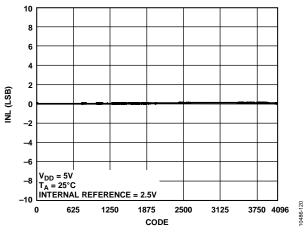


Figure 15. AD5694R INL

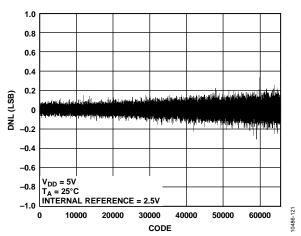


Figure 16. AD5696R DNL

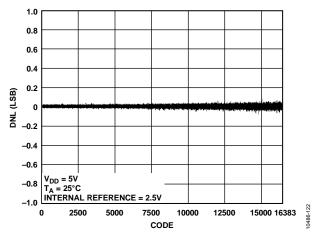


Figure 17. AD5695R DNL

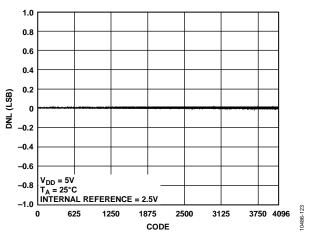


Figure 18. AD5694R DNL

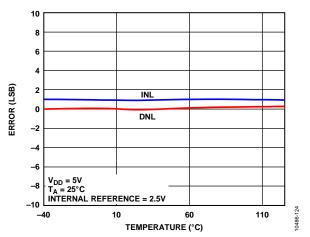


Figure 19. INL Error and DNL Error vs. Temperature

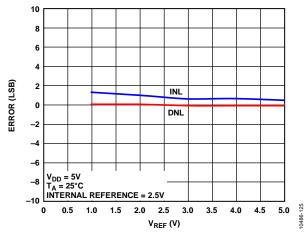


Figure 20. INL Error and DNL Error vs. V_{REF}

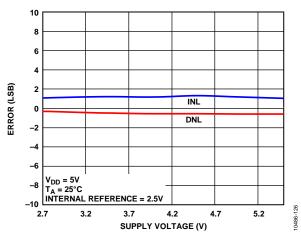


Figure 21. INL Error and DNL Error vs. Supply Voltage

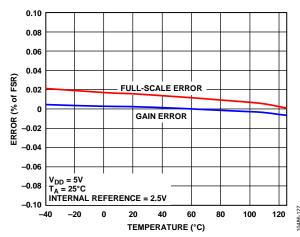


Figure 22. Gain Error and Full-Scale Error vs. Temperature

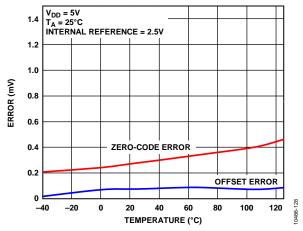


Figure 23. Zero-Code Error and Offset Error vs. Temperature

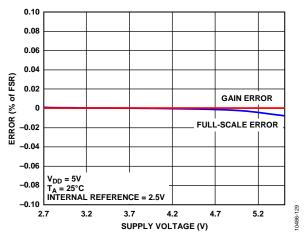


Figure 24. Gain Error and Full-Scale Error vs. Supply

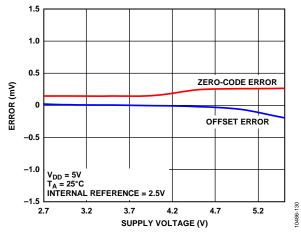


Figure 25. Zero-Code Error and Offset Error vs. Supply

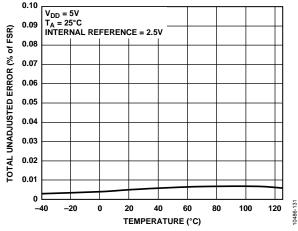


Figure 26. TUE vs. Temperature

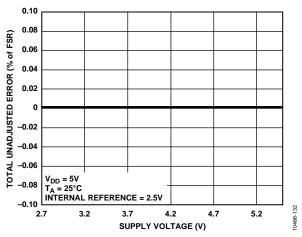


Figure 27. TUE vs. Supply, Gain = 1

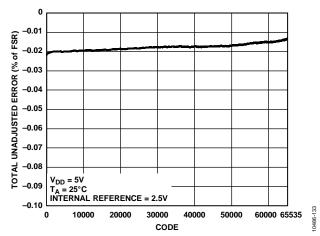


Figure 28. TUE vs. Code

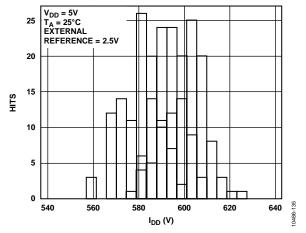


Figure 29. IDD Histogram with External Reference, 5 V

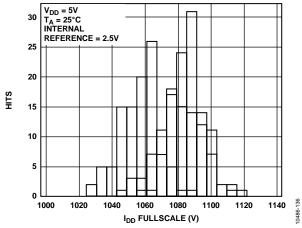


Figure 30. I_{DD} Histogram with Internal Reference, $V_{REFOUT} = 2.5 V$, Gain = 2

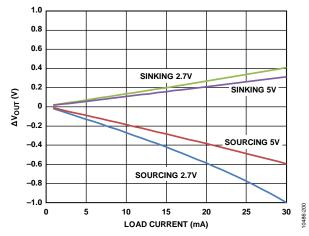


Figure 31. Headroom/Footroom vs. Load Current

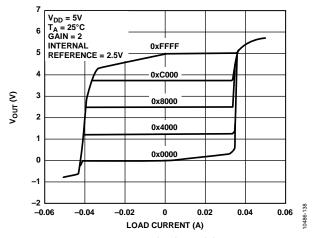


Figure 32. Source and Sink Capability at 5 V

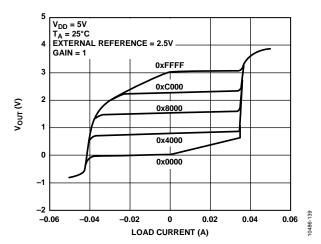


Figure 33. Source and Sink Capability at 3 V

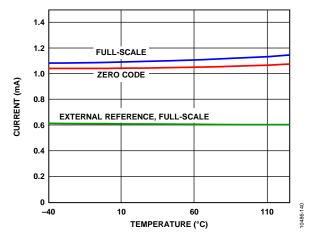


Figure 34. Supply Current vs. Temperature

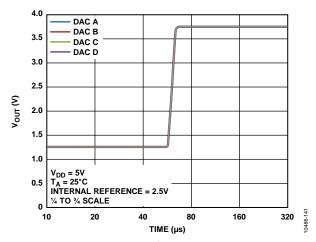


Figure 35. Settling Time, 5.25 V

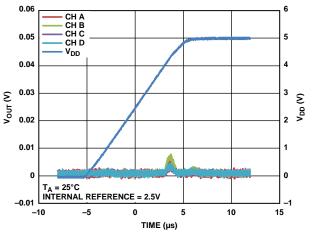


Figure 36. Power-On Reset to 0 V

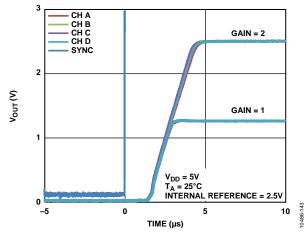


Figure 37. Exiting Power-Down to Midscale

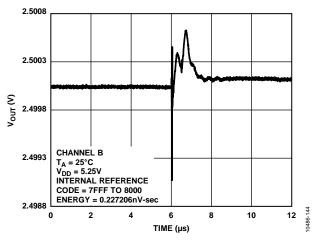


Figure 38. Digital-to-Analog Glitch Impulse

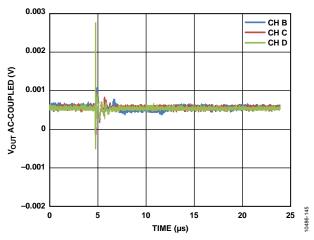


Figure 39. Analog Crosstalk, Channel A

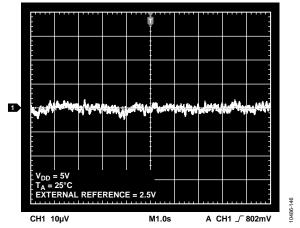


Figure 40. 0.1 Hz to 10 Hz Output Noise Plot, External Reference

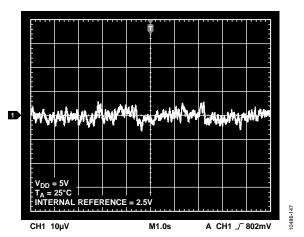


Figure 41. 0.1 Hz to 10 Hz Output Noise Plot, 2.5 V Internal Reference

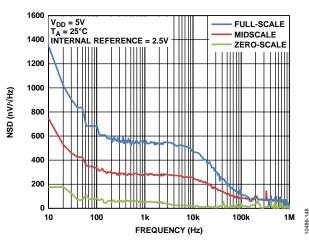


Figure 42. Noise Spectral Density

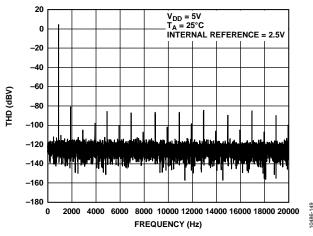


Figure 43. Total Harmonic Distortion @ 1 kHz

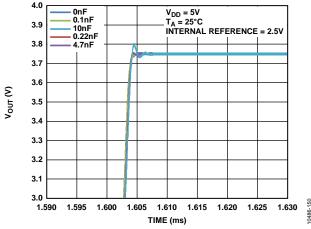


Figure 44. Settling Time vs. Capacitive Load

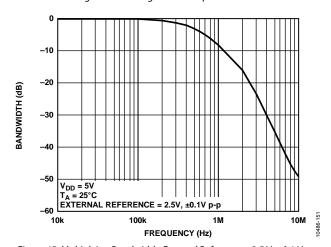


Figure 45. Multiplying Bandwidth, External Reference = 2.5 V, ± 0.1 V p-p, 10 kHz to 10 MHz

TERMINOLOGY

Relative Accuracy or Integral Nonlinearity (INL)

For the DAC, relative accuracy or integral nonlinearity is a measurement of the maximum deviation, in LSBs, from a straight line passing through the endpoints of the DAC transfer function. A typical INL vs. code plot is shown in Figure 13.

Differential Nonlinearity (DNL)

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of ± 1 LSB maximum ensures monotonicity. This DAC is guaranteed monotonic by design. A typical DNL vs. code plot can be seen in Figure 16.

Zero-Code Error

Zero-code error is a measurement of the output error when zero code (0x0000) is loaded to the DAC register. Ideally, the output should be 0 V. The zero-code error is always positive in the AD5696R because the output of the DAC cannot go below 0 V due to a combination of the offset errors in the DAC and the output amplifier. Zero-code error is expressed in mV. A plot of zero-code error vs. temperature can be seen in Figure 23.

Full-Scale Error

Full-scale error is a measurement of the output error when full-scale code (0xFFFF) is loaded to the DAC register. Ideally, the output should be $V_{\rm DD}-1$ LSB. Full-scale error is expressed in percent of full-scale range (% of FSR). A plot of full-scale error vs. temperature can be seen in Figure 22.

Gain Error

This is a measure of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from the ideal expressed as % of FSR.

Offset Error Drift

This is a measurement of the change in offset error with a change in temperature. It is expressed in $\mu V/^{\circ}C$.

Gain Temperature Coefficient

This is a measurement of the change in gain error with changes in temperature. It is expressed in ppm of FSR/°C.

Offset Error

Offset error is a measure of the difference between V_{OUT} (actual) and V_{OUT} (ideal) expressed in mV in the linear region of the transfer function. Offset error is measured on the AD5696R with Code 512 loaded in the DAC register. It can be negative or positive.

DC Power Supply Rejection Ratio (PSRR)

This indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is the ratio of the change in V_{OUT} to a change in V_{DD} for full-scale output of the DAC. It is measured in mV/V. V_{REF} is held at 2 V, and V_{DD} is varied by $\pm 10\%$.

Output Voltage Settling Time

This is the amount of time it takes for the output of a DAC to settle to a specified level for a ¼ to ¾ full-scale input change.

Digital-to-Analog Glitch Impulse

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nV-sec, and is measured when the digital input code is changed by 1 LSB at the major carry transition (0x7FFF to 0x8000) (see Figure 38).

Digital Feedthrough

Digital feedthrough is a measure of the impulse injected into the analog output of the DAC from the digital inputs of the DAC, but is measured when the DAC output is not updated. It is specified in nV-sec, and measured with a full-scale code change on the data bus, that is, from all 0s to all 1s and vice versa.

Reference Feedthrough

Reference feedthrough is the ratio of the amplitude of the signal at the DAC output to the reference input when the DAC output is not being updated. It is expressed in dB.

Noise Spectral Density

This is a measurement of the internally generated random noise. Random noise is characterized as a spectral density (nV/\sqrt{Hz}) . It is measured by loading the DAC to midscale and measuring noise at the output. It is measured in nV/\sqrt{Hz} . A plot of noise spectral density is shown in Figure 42.

DC Crosstalk

DC crosstalk is the dc change in the output level of one DAC in response to a change in the output of another DAC. It is measured with a full-scale output change on one DAC (or soft power-down and power-up) while monitoring another DAC kept at midscale. It is expressed in μV .

DC crosstalk due to load current change is a measure of the impact that a change in load current on one DAC has to another DAC kept at midscale. It is expressed in $\mu V/mA$.

Digital Crosstalk

This is the glitch impulse transferred to the output of one DAC at midscale in response to a full-scale code change (all 0s to all 1s and vice versa) in the input register of another DAC. It is measured in standalone mode and is expressed in nV-sec.

Analog Crosstalk

This is the glitch impulse transferred to the output of one DAC due to a change in the output of another DAC. It is measured by loading one of the input registers with a full-scale code change (all 0s to all 1s and vice versa). Then execute a software LDAC and monitor the output of the DAC whose digital code was not changed. The area of the glitch is expressed in nV-sec.

DAC-to-DAC Crosstalk

This is the glitch impulse transferred to the output of one DAC due to a digital code change and subsequent analog output change of another DAC. It is measured by loading the attack channel with a full-scale code change (all 0s to all 1s and vice versa), using the write to and update commands while monitoring the output of the victim channel that is at midscale. The energy of the glitch is expressed in nV-sec.

Multiplying Bandwidth

The amplifiers within the DAC have a finite bandwidth. The multiplying bandwidth is a measure of this. A sine wave on the reference (with full-scale code loaded to the DAC) appears on the output. The multiplying bandwidth is the frequency at which the output amplitude falls to 3 dB below the input.

Total Harmonic Distortion (THD)

This is the difference between an ideal sine wave and its attenuated version using the DAC. The sine wave is used as the reference for the DAC, and the THD is a measurement of the harmonics present on the DAC output. It is measured in dB.

Voltage Reference TC

Voltage reference TC is a measure of the change in the reference output voltage with a change in temperature. The reference TC is calculated using the box method, which defines the TC as the maximum change in the reference output over a given temperature range expressed in ppm/°C as follows;

$$TC = \left\lceil \frac{V_{REFmax} - V_{REFmin}}{V_{REFnom} \times TempRange} \right\rceil \times 10^{6}$$

where:

 V_{REFmax} is the maximum reference output measured over the total temperature range.

 $V_{\it REFmin}$ is the minimum reference output measured over the total temperature range.

 V_{REFnom} is the nominal reference output voltage, 2.5 V. *TempRange* is the specified temperature range of -40° C to $+105^{\circ}$ C.

THEORY OF OPERATION DIGITAL-TO-ANALOG CONVERTER

The AD5696R/AD5695R/AD5694R are quad 16-/14-/12-bit, serial input, voltage output DACs with an internal reference. The parts operate from supply voltages of 2.7 V to 5.5 V. Data is written to the AD5696R/AD5695R/AD5694R in a 24-bit word format via a 2-wire serial interface. The AD5696R/AD5695R/AD5694R incorporate a power-on reset circuit to ensure that the DAC output powers up to a known output state. The devices also have a software power-down mode that reduces the typical current consumption to typically 4 μA .

TRANSFER FUNCTION

The internal reference is on by default. To use an external reference, only a nonreference option is available. Because the input coding to the DAC is straight binary, the ideal output voltage when using an external reference is given by

$$V_{OUT} = V_{REF} \times Gain\left[\frac{D}{2^N}\right]$$

where:

D is the decimal equivalent of the binary code that is loaded to the DAC register as follows:

0 to 4,095 for the 12-bit device.

0 to 16,383 for the 14-bit device.

0 to 65,535 for the 16-bit device.

N is the DAC resolution.

Gain is the gain of the output amplifier and is set to 1 by default. This can be set to $\times 1$ or $\times 2$ using the gain select pin. When this pin is tied to GND, all four DAC outputs have a span from 0 V to V_{REF} . If this pin is tied to V_{DD} , all four DACs output a span of 0 V to 2 \times V_{REF} .

DAC ARCHITECTURE

The DAC architecture consists of a string DAC followed by an output amplifier. Figure 46 shows a block diagram of the DAC architecture.

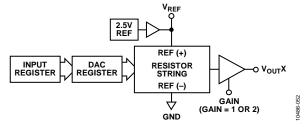


Figure 46. Single DAC Channel Architecture Block Diagram

The resistor string structure is shown in Figure 47. It is a string of resistors, each of Value R. The code loaded to the DAC register determines the node on the string where the voltage is to be tapped off and fed into the output amplifier. The voltage is tapped off by closing one of the switches connecting the string to the amplifier. Because it is a string of resistors, it is guaranteed monotonic.

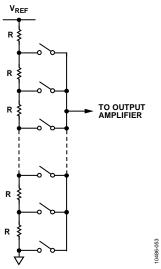


Figure 47. Resistor String Structure

Internal Reference

The AD5696R/AD5695R/AD5694R on-chip reference is on at power-up but can be disabled via a write to a control register. See the Internal Reference Setup section for details.

The AD5696R/AD5695R/AD5694R have a 2.5 V, 2 ppm/°C reference, giving a full-scale output of 2.5 V or 5 V depending on the state of the GAIN pin. The internal reference associated with the device is available at the V_{REF} pin. This buffered reference is capable of driving external loads of up to 10 mA.

Output Amplifiers

The output buffer amplifier can generate rail-to-rail voltages on its output, which gives an output range of 0 V to $V_{\rm DD}$. The actual range depends on the value of $V_{\rm REF}$, the GAIN pin, offset error, and gain error. The GAIN pin selects the gain of the output.

- If this pin is tied to GND, all four outputs have a gain of 1 and the output range is 0 V to V_{REF} .
- If this pin is tied to V_{LOGIC} , all four outputs have a gain of 2 and the output range is 0 V to $2 \times V_{REF}$.

These amplifiers are capable of driving a load of 1 k Ω in parallel with 2 nF to GND. The slew rate is 0.8 V/ μ s with a $\frac{1}{4}$ to $\frac{3}{4}$ scale settling time of 5 μ s.

SERIAL INTERFACE

The AD5696R/AD5695R/AD5694R have 2-wire I²C-compatible serial interfaces (refer to *I*²C-Bus Specification, Version 2.1, January 2000, available from Philips Semiconductor). See Figure 2 for a timing diagram of a typical write sequence. The AD5696R/AD5695R/AD5694R can be connected to an I²C bus as a slave device, under the control of a master device. The AD5696R/AD5695R/AD5694R support standard (100 kHz) and fast (400 kHz) data transfer modes. Support is not provided for 10-bit addressing and general call addressing.

Input Shift Register

The input shift register of the AD5696R/AD5695R/AD5694R is 24 bits wide. Data is loaded into the device as a 24-bit word under the control of a serial clock input, SCL. The first eight MSBs make up the command byte. The first four bits are the command bits (C3, C2, C1, C0) that control the mode of operation of the device (see Table 7). The last 4 bits of first byte are the address bits (DAC A, DAC B, DAC C, DAC D) (see Table 8).

The data-word comprises 16-bit, 14-bit, or 12-bit input code, followed by four, two, or zero don't care bits for the AD5696R, AD5695R, and AD5694R, respectively (see Figure 48, Figure 49, and Figure 50). These data bits are transferred to the input register on the 24 falling edges of SCL.

Commands can be executed on individual DAC channels, combined DAC channels, or on all DACs, depending on the address bits selected.

Table 7. Command Definitions

	Comi	mand							
С3	C2	C1	CO	Description					
0	0	0	0	No operation					
0	0	0	1	Write to Input Register n (dependent on LDAC)					
0	0	1	0	No operation Write to Input Register n (dependent on LDAC) Update DAC Register n with contents of Input Register n Write to and update DAC Channel n Power down/power up DAC Hardware LDAC mask register Software reset (power-on reset) Internal reference setup register Reserved					
0	0	1	1	•					
0	1	0	0	Update DAC Register n with contents of Input Register n Write to and update DAC Channel n Power down/power up DAC Hardware LDAC mask register Software reset (power-on reset) Internal reference setup register					
0	1	0	1	Hardware LDAC mask register					
0	1	1	0	Write to Input Register n (dependent on LDA) Update DAC Register n with contents of Inpu Register n Write to and update DAC Channel n Power down/power up DAC Hardware LDAC mask register Software reset (power-on reset) Internal reference setup register					
0	1	1	1	Internal reference setup register					
1	0	0	0	Reserved					
				Reserved					
1	1	1	1	Reserved					

Table 8. Address Commands

	Addr	ess (n)		
DAC D	DACC	DAC B	DAC A	Selected DAC Channel ¹
0	0	0	1	DAC A
0	0	1	0	DAC B
0	1	0	0	DAC C
1	0	0	0	DAC D
0	0	1	1	DAC A and DAC B ¹
1	1	1	1	All DACs

¹ Any combination of DAC channels can be selected using the address bits.

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15 DB14 DB13 DB12 DB11 DB10 DB9 DB8 I							DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0	
C3	C2	C1	C0	DAC D	DAC C	DAC B	DAC A	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	х	х	х
	СОМІ	MAND		ı	DAC AE	DDRESS	3		DAC DATA						DAC DATA								
COMMAND BYTE					DATA HIGH BYTE						DATA LOW BYTE												

Figure 48. AD5696R Input Shift Register Content

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
C3	C2	C1	C0	DAC D	DAC C	DAC B	DAC A	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х
COMMAND				DAC ADDRESS				DAC DATA						DAC DATA									
	COMMAND BYTE					DATA HIGH BYTE					DATA LOW BYTE												

Figure 49. AD5695R Input Shift Register Content

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
С3	C2	C1	C0	DAC D	DAC C	DAC B	DAC A	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
COMMAND DAC ADDRESS					3	DAC DATA							DAC DATA										
COMMAND BYTE					DATA HIGH BYTE						DATA LOW BYTE												

Figure 50. AD5694R Input Shift Register Content

WRITE AND UPDATE COMMANDS

Write to Input Register n (Dependent on LDAC)

Command 0001 allows the user to write to each DAC's dedicated input register individually. When \overline{LDAC} is low, the input register is transparent (if not controlled by the \overline{LDAC} mask register).

Update DAC Register n with Contents of Input Register n

Command 0010 loads the DAC registers/outputs with the contents of the input registers selected and updates the DAC outputs directly.

$\frac{\textit{Write}}{\textit{LDAC}} \ \textit{to and Update DAC Channel n (Independent of LDAC)}$

Command 0011 allows the user to write to the DAC registers and update the DAC outputs directly.

SERIAL OPERATION

The AD5696R/AD5695R/AD5694R each have a 7-bit slave address. The five MSBs are 00011 and the two LSBs (A1, A0) are set by the state of the A0 and A1 address pins. The ability to make hardwired changes to A0 and A1 allows the user to incorporate up to four of these devices on one bus, as outlined in Table 9.

Table 9. Device Address Selection

A0 Pin Connection	A1 Pin Connection	AO	A1
GND	GND	0	0
V_{LOGIC}	GND	1	0
GND	V _{LOGIC}	0	1
V_{LOGIC}	V _{LOGIC}	1	1

The 2-wire serial bus protocol operates as follows:

1. The master initiates data transfer by establishing a start condition when a high-to-low transition on the SDA line occurs while SCL is high. The following byte is the address byte, which consists of the 7-bit slave address. The slave address corresponding to the transmitted address responds by pulling SDA low during the 9th clock pulse (this is termed the acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to, or read from, its shift register.

- Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit). The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL.
- 3. When all data bits have been read or written, a stop condition is established. In write mode, the master pulls the SDA line high during the 10th clock pulse to establish a stop condition. In read mode, the master issues a no acknowledge for the 9th clock pulse (that is, the SDA line remains high). The master then brings the SDA line low before the 10th clock pulse, and then high during the 10th clock pulse to establish a stop condition.

WRITE OPERATION

When writing to the AD5696R/AD5695R/AD5694R, the user must begin with a start command followed by an address byte $(R/\overline{W}=0)$, after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The AD5696R/AD5695R/AD5694R require two bytes of data for the DAC and a command byte that controls various DAC functions. Three bytes of data must, therefore, be written to the DAC with the command byte followed by the most significant data byte and the least significant data byte, as shown in Figure 51. All these data bytes are acknowledged by the AD5696R/AD5695R/AD5694R. A stop condition follows.

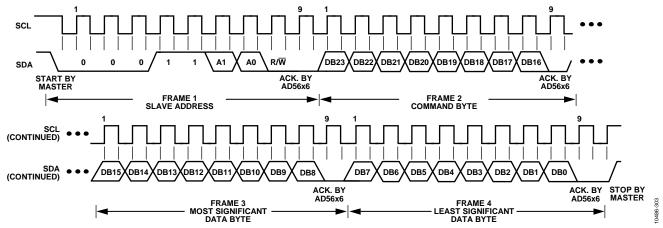


Figure 51. I²C Write Operation

READ OPERATION

When reading data back from the AD5696R DACs, the user begins with an address byte (R/ \overline{W} = 0), after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. This address byte must be followed by the control byte that determines both the read command that is to follow and the pointer address to read from, which is also acknowledged by the DAC. The user configures which channel to read back and sets the readback command to active using the control byte. Following this, there is a repeated start condition by the master and the address is resent with R/\overline{W} = 1. This is acknowledged by the DAC, indicating that it is prepared to transmit data. Two bytes of data are then read from the DAC, as shown in Figure 52. A NACK condition from the master, followed by a STOP condition, completes the read sequence. Default readback is Channel A if more than one DAC is selected.

MULTIPLE DAC READBACK SEQUENCE

The user begins with an address byte $(R/\overline{W} = 0)$, after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. This address byte must be followed by the control byte, which is also acknowledged by the DAC. The user configures which channel to start the readback using the control byte. Following this, there is a repeated start condition by the master and the address is resent with $R/\overline{W} = 1$. This is acknowledged by the DAC, indicating that it is prepared to transmit data. The first two bytes of data are then read from the DAC Input Register n selected using the control byte, most significant byte first as shown in Figure 52. The next two bytes read back are the contents of DAC Input Register n + 1, the next bytes read back are the contents of DAC Input Register n + 2. Data continues to be read from the DAC input registers in this auto-incremental fashion, until a NACK followed by a stop condition follows. If the contents of DAC Input Register D are read out, the next two bytes of data that are read are from the contents of DAC Input Register A.

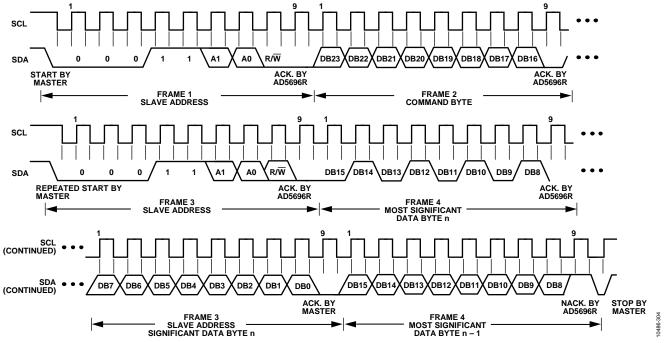


Figure 52. I²C Read Operation

POWER-DOWN OPERATION

The AD5696R/AD5695R/AD5694R contain three separate power-down modes. Command 0100 is designated for the power-down function (see Table 7). These power-down modes are software-programmable by setting eight bits, Bit DB7 to Bit DB0, in the shift register. There are two bits associated with each DAC channel. Table 10 shows how the state of the two bits corresponds to the mode of operation of the device.

Table 10. Modes of Operation

Operating Mode	PDx1	PDx0
Normal Operation	0	0
Power-Down Modes		
1 kΩ to GND	0	1
100 k Ω to GND	1	0
Three-State	1	1

Any or all DACs (DAC A to DAC D) can be powered down to the selected mode by setting the corresponding bits. See Table 11 for the contents of the input shift register during the power-down/power-up operation.

When both Bit PDx1 and Bit PDx0 (where x is the channel selected) in the input shift register are set to 0, the parts work normally with its normal power consumption of 4 mA at 5 V. However, for the three power-down modes, the supply current falls to 4 μ A at 5 V. Not only does the supply current fall, but the

output stage is also internally switched from the output of the amplifier to a resistor network of known values. This has the advantage that the output impedance of the part is known while the part is in power-down mode. There are three different power-down options. The output is connected internally to GND through either a 1 k Ω or a 100 k Ω resistor, or it is left open-circuited (three-state). The output stage is illustrated in Figure 53.

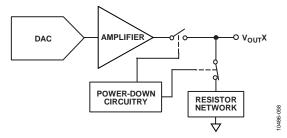


Figure 53. Output Stage During Power-Down

The bias generator, output amplifier, resistor string, and other associated linear circuitry are shut down when the power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The DAC register can be updated while the device is in power-down mode. The time required to exit power-down is typically 4.5 μ s for $V_{\rm DD} = 5$ V.

To reduce the current consumption further, the on-chip reference can be powered off. See the Internal Reference Setup section.

Table 11. 24-Bit Input Shift Register Contents of Power-Down/Power-Up Operation¹

DB23	DB22	DB21	DB20	DB19 to DB16	DB15 to DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0 (LSB)
0	1	0	0	Х	Х	PDD1	PDD0	PDC1	PDC0	PDB1	PDB0	PDA1	PDA0
Command bits (C3 to C0)			Address bits Don't care			-Down DAC D		-Down DAC C	Power- Select		Power- Select		

¹ X = don't care.

LOAD DAC (HARDWARE LDAC PIN)

The AD5696R/AD5695R/AD5694R DACs have double buffered interfaces consisting of two banks of registers: input registers and DAC registers. The user can write to any combination of the input registers. Updates to the DAC register are controlled by the LDAC pin.

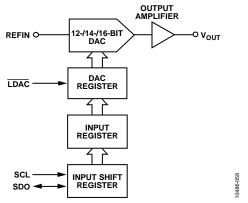


Figure 54. Simplified Diagram of Input Loading Circuitry for a Single DAC

Instantaneous DAC Updating (LDAC Held Low)

LDAC is held low while data is clocked into the input register using Command 0001. Both the addressed input register and the DAC register are updated on the 24th clock and the output begins to change (see Table 13).

Deferred DAC Updating (LDAC is Pulsed Low)

 $\overline{\text{LDAC}}$ is held high while data is clocked into the input register using Command 0001. All DAC outputs are asynchronously updated by taking $\overline{\text{LDAC}}$ low after the 24th clock. The update now occurs on the falling edge of $\overline{\text{LDAC}}$.

Table 13. Write Commands and LDAC Pin Truth Table¹

Hardware LDAC **Input Register Commands** Description **Pin State Contents DAC Register Contents** 0001 Write to Input Register n (dependent on LDAC) No change (no update) V_{LOGIC} Data update GND² Data update Data update 0010 Update DAC Register n with contents of Input No change Updated with input register V_{LOGIC} Register n contents GND No change Updated with input register contents Write to and update DAC Channel n 0011 VLOGIC Data update Data update **GND** Data update Data update

LDAC MASK REGISTER

Command 0101 is reserved for this software \overline{LDAC} function. Address bits are ignored. Writing to the DAC, using Command 0101, loads the 4-bit \overline{LDAC} register (DB3 to DB0). The default for each channel is 0; that is, the \overline{LDAC} pin works normally. Setting the bits to 1 forces this DAC channel to ignore transitions on the \overline{LDAC} pin, regardless of the state of the hardware \overline{LDAC} pin. This flexibility is useful in applications where the user wishes to select which channels respond to the \overline{LDAC} pin.

Table 12. LDAC Overwrite Definition

Load LDAC	Register	
LDAC Bits (DB3 to DB0)	LDAC Pin	LDAC Operation
0	1 or 0	Determined by the LDAC pin.
1	X ¹	DAC channels update and override the LDAC pin. DAC channels see LDAC as 1.

 $^{^{1}}$ X = don't care.

The LDAC register gives the user extra flexibility and control over the hardware LDAC pin (see Table 12). Setting the LDAC bits (DB0 to DB3) to 0 for a DAC channel means that this channel's update is controlled by the hardware LDAC pin.

¹ A high to low hardware LDAC pin transition always updates the contents of the contents of the DAC register with the contents of the input register on channels that are not masked (blocked) by the LDAC mask register.

² When LDAC is permanently tied low, the LDAC mask bits are ignored.

HARDWARE RESET (RESET)

RESET is an active low reset that allows the outputs to be cleared to either zero scale or midscale. The clear code value is user selectable via the RESET select pin. It is necessary to keep RESET low for a minimum amount of time to complete the operation (see Figure 2). When the RESET signal is returned high, the output remains at the cleared value until a new value is programmed. The outputs cannot be updated with a new value while the RESET pin is low. There is also a software executable reset function that resets the DAC to the power-on reset code. Command 0110 is designated for this software reset function (see Table 7). Any events on LDAC or RESET during power-on reset are ignored.

RESET SELECT PIN (RSTSEL)

The AD5696R/AD5695R/AD5694R contain a power-on reset circuit that controls the output voltage during power-up. By connecting the RSTSEL pin low, the output powers up to zero scale. Note that this is outside the linear region of the DAC; by connecting the RSTSEL pin high, V_{OUT} powers up to midscale. The output remains powered up at this level until a valid write sequence is made to the DAC.

INTERNAL REFERENCE SETUP

The on-chip reference is on at power-up by default. To reduce the supply current, this reference can be turned off by setting software programmable bit, DB0, in the control register. Table 14 shows how the state of the bit corresponds to the mode of operation. Command 0111 is reserved for setting up the internal reference (see Figure 6). Table 14 shows how the state of the bits in the input shift register corresponds to the mode of operation of the device during internal reference setup.

Table 14. Reference Setup Register

Internal Reference Setup Register (DB0)	Action
0	Reference on (default)
1	Reference off

SOLDER HEAT REFLOW

As with all IC reference voltage circuits, the reference value experiences a shift induced by the soldering process. Analog Devices, Inc., performs a reliability test called precondition to mimic the effect of soldering a device to a board. The output voltage specification quoted previously includes the effect of this reliability test.

Figure 55 shows the effect of solder heat reflow (SHR) as measured through the reliability test (precondition).

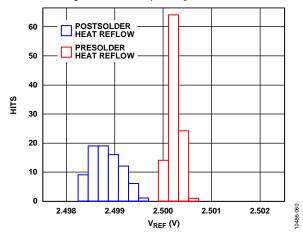


Figure 55. SHR Reference Voltage Shift

LONG-TERM TEMPERATURE DRIFT

Figure 56 shows the change in V_{REF} value after 1000 hours in life test at 150°C.

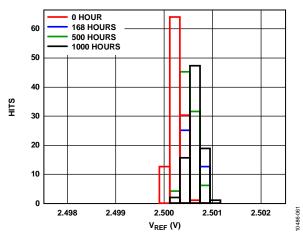


Figure 56. Reference Drift Through to 1000 Hours

THERMAL HYSTERESIS

Thermal hysteresis is the voltage difference induced on the reference voltage by sweeping the temperature from ambient to cold, to hot and then back to ambient.

Thermal hysteresis data is shown in Figure 57. It is measured by sweeping temperature from ambient to -40° C, then to $+105^{\circ}$ C, and returning to ambient. The V_{REF} delta is then measured between the two ambient measurements and shown in blue in Figure 57. The same temperature sweep and measurements were immediately repeated and the results are shown in red in Figure 57.

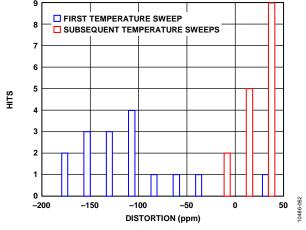


Figure 57. Thermal Hysteresis

Table 15. 24-Bit Input Shift Register Contents for Internal Reference Setup Command¹

DB23 (MSB)	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15 to DB1	DB0 (LSB)
0	1 1 1		1	X X X X			Χ	X	1/0
Cor	nmand b	its (C3 to (CO)	А	ddress bit	s (A2 to A	0)	Don't care	Reference setup register

 $^{^{1}}$ X = don't care.

APPLICATIONS INFORMATION MICROPROCESSOR INTERFACING

Microprocessor interfacing to the AD5696R/AD5695R/AD5694R is via a serial bus that uses a standard protocol that is compatible with DSP processors and microcontrollers. The communications channel requires a 2-wire interface consisting of a clock signal and a data signal.

AD5696R/AD5695R/AD5694R TO ADSP-BF531 INTERFACE

The I²C interface of the AD5696R/AD5695R/AD5694R is designed to be easily connected to industry-standard DSPs and microcontrollers. Figure 58 shows the AD5696R/AD5695R/AD5694R connected to the Analog Devices Blackfin* DSP. The Blackfin has an integrated I²C port that can be connected directly to the I²C pins of the AD5696R/AD5695R/AD5694R.

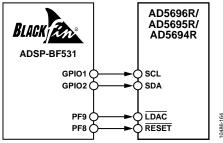


Figure 58. ADSP-BF531 Interface

LAYOUT GUIDELINES

In any circuit where accuracy is important, careful consideration of the power supply and ground return layout helps to ensure the rated performance. The PCB on which the AD5696R/AD5695R/AD5694R are mounted should be designed so that the AD5696R/AD5695R/AD5694R lie on the analog plane.

The AD5696R/AD5695R/AD5694R should have ample supply bypassing of 10 μF in parallel with 0.1 μF on each supply, located as close to the package as possible, ideally right up against the device. The 10 μF capacitors are the tantalum bead type. The 0.1 μF capacitor should have low effective series resistance (ESR) and low effective series inductance (ESI) such as the common ceramic types, which provide a low impedance path to ground at high frequencies to handle transient currents due to internal logic switching.

In systems where there are many devices on one board, it is often useful to provide some heat sinking capability to allow the power to dissipate easily.

The AD5696R/AD5695R/AD5694R LFCSP models have an exposed paddle beneath the device. Connect this paddle to the GND supply for the part. For optimum performance, use

special considerations to design the motherboard and to mount the package. For enhanced thermal, electrical, and board level performance, solder the exposed paddle on the bottom of the package to the corresponding thermal land paddle on the PCB. Design thermal vias into the PCB land paddle area to further improve heat dissipation.

The GND plane on the device can be increased (as shown in Figure 59) to provide a natural heat sinking effect.

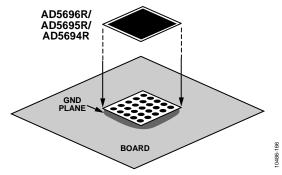
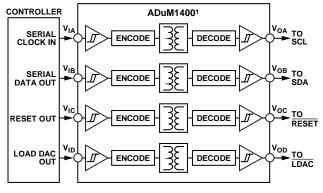


Figure 59. Paddle Connection to Board

GALVANICALLY ISOLATED INTERFACE

In many process control applications, it is necessary to provide an isolation barrier between the controller and the unit being controlled to protect and isolate the controlling circuitry from any hazardous common-mode voltages that may occur. *i*Coupler* products from Analog Devices provide voltage isolation in excess of 2.5 kV. The serial loading structure of the AD5696R/AD5695R/AD5694R makes the part ideal for isolated interfaces because the number of interface lines is kept to a minimum. Figure 60 shows a 4-channel isolated interface to the AD5696R/AD5695R/AD5694R using an ADuM1400. For further information, visit http://www.analog.com/icouplers.



¹ADDITIONAL PINS OMITTED FOR CLARITY.

Figure 60. Isolated Interface

10486-167

OUTLINE DIMENSIONS

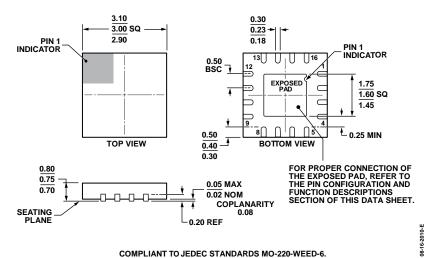


Figure 61. 16-Lead Lead Frame Chip Scale Package [LFCSP_WQ] 3 mm × 3 mm Body, Very Very Thin Quad

(CP-16-22)
Dimensions shown in millimeters

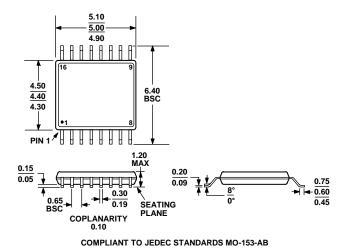


Figure 62. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16) Dimensions shown in millimeters

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ORDERING GUIDE

		_		Reference			
Model ¹	Resolution	Temperature Range	Accuracy	Tempco (ppm/°C)	Package Description	Package Option	Branding
AD5696RACPZ-RL7	16 Bits	-40°C to +105°C	±8 LSB INL	±5 (typ)	16-Lead LFCSP_WQ	CP-16-22	DJA
AD5696RBCPZ-RL7	16 Bits	-40°C to +105°C	±2 LSB INL	±5 (max)	16-Lead LFCSP_WQ	CP-16-22	DJD
AD5696RARUZ	16 Bits	-40°C to +105°C	±8 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5696RARUZ-RL7	16 Bits	-40°C to +105°C	±8 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5696RBRUZ	16 Bits	-40°C to +105°C	±2 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5696RBRUZ-RL7	16 Bits	-40°C to +105°C	±2 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5695RBCPZ-RL7	14 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead LFCSP_WQ	CP-16-22	DJR
AD5695RARUZ	14 Bits	-40°C to +105°C	±4 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5695RARUZ-RL7	14 Bits	-40°C to +105°C	±4 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5695RBRUZ	14 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5695RBRUZ-RL7	14 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5694RBCPZ-RL7	12 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead LFCSP_WQ	CP-16-22	DJL
AD5694RARUZ	12 Bits	-40°C to +105°C	±2 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5694RARUZ-RL7	12 Bits	-40°C to +105°C	±2 LSB INL	±5 (typ)	16-Lead TSSOP	RU-16	
AD5694RBRUZ	12 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
AD5694RBRUZ-RL7	12 Bits	-40°C to +105°C	±1 LSB INL	±5 (max)	16-Lead TSSOP	RU-16	
EVAL-AD5696RSDZ					AD5696RTSSOP		
					Evaluation Board		
EVAL-AD5694RSDZ					AD5694R TSSOP		
					Evaluation Board		

 $^{^{1}}$ Z = RoHS Compliant Part.

NOTES

Data Sheet

AD5696R/AD5695R/AD5694R

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Data Sheet

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